ON Semiconductor

Is Now



To learn more about onsemi™, please visit our website at www.onsemi.com

onsemi and ONSEMI. and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. onsemi reserves the right to make changes at any time to any products or information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/ or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use onsemi products for any such unintended or unauthorized application,

Advance Information Auto Focus (AF) Controller

ON Semiconductor®

www.onsemi.com

Overview

This LSI is Closed-Auto Focus control LSI equipped with hall sensor. It consists of 1 system feedback circuit and constant current driver. It has also a built-in EEPROM and temperature sensor.

Features

- Built-in equalizer circuit using digital operation
- AF control equalizer circuit
- Any coefficient can be specified by 2-wire serial I/F (TWIF)
- 2-wire serial interface

 (The communication protocol is compatible with I²C.)
- Built-in A/D converter
- Built-in D/A converter
- Hall offset
- Constant current bias
- Built-in Hall Sensor
- Si Hall sensor
- Built-in VGA
- Hall Amp
- Built-in EEPROM
- 128 byte (16 byte/page)
- Built-in OSC
- Built-in Constant Current Driver
- 140 mA
- Package
- WL-CSP 8-pin
- Pb-Free, Halogen Free
- Supply voltage
- V_{DD} (2.6 V to 3.3 V)



WLCSP8, 0.97x2.25x0.265

This document contains information on a new product. Specifications and information herein are subject to change without notice.

ORDERING INFORMATION

See detailed ordering and shipping information on page 9 of this data sheet.

Pin Description

TYPE							
I	INPUT	Р	Power supply, GND	NC	NOT CONNECT		
0	OUTPUT						
В	BIDIRECTION						

■ 2-wire serial interface

SCL I 2-wire serial interface clock pin SDA B 2-wire serial interface data pin

■ Driver interface

OUT1 O Driver output (to Actuator)
OUT2 O Driver output (to Actuator)

■ Power supply pin

VDD P Power supply

VSS P GND

■ Port pin

PORT B Convergence detection monitor output

VSYNC input Test pin

■ Test pin

TEST O Test pin

*Process when pins are not used

PIN TYPE "O" – Ensure that it is set to OPEN.

PIN TYPE "I" – OPEN is inhibited. Ensure that it is connected to the V_{DD} or V_{SS} even when it is unused.

(Please contact ON Semiconductor for more information about selection of V_{DD} or V_{SS}.)

PIN TYPE "B" – If you are unsure about processing method on the pin description of pin layout table, please contact us.

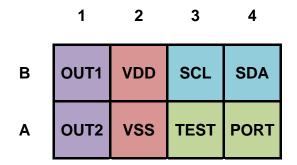
Note that incorrect processing of unused pins may result in defects.

*In case of connecting PORT pin with HOST CPU

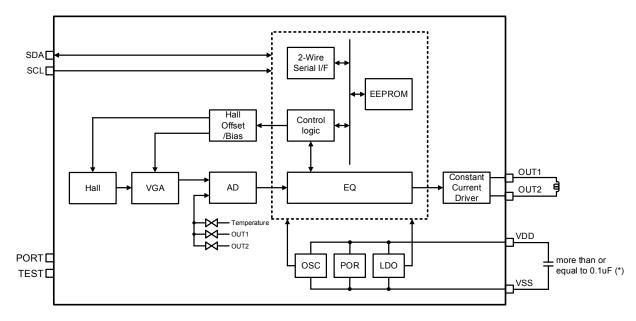
When LC898219XI is power off and HOST CPU is power on, a HOST CPU pin connected with PORT pin have to be fixed "L" level.

Pin Layout

BOTTOM VIEW



Block Diagram



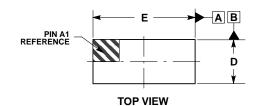
(*): Consider capacitance of capacitor between $V_{\mbox{DD}}$ and $V_{\mbox{SS}}$. According to power source environment, attach an additional capacitor in camera module.

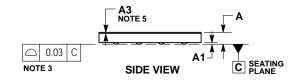
Package Dimensions

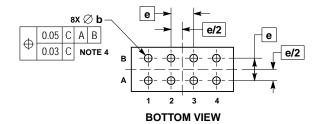
unit: mm

WLCSP8, 0.97x2.25X0.265

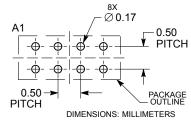
CASE 567TE ISSUE A







RECOMMENDED SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

NOTES:

- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

 2. CONTROLLING DIMENSION: MILLIMETERS.

 3. COPLANARITY APPLIES TO THE SPHERICAL CROWNS OF THE SOLDER BALLS.

 4. DIMENSION b IS MEASURED AT THE MAXIMUM BALL DIAMETER PARALLEL TO DATUM C.

 5. DIMENSION A3 IS AN OPTIONAL BACKSIDE COATING LAYER.

	MILLIMETERS						
DIM	MIN	MAX					
Α	0.24 0.265 0.						
A1	0.04 REF						
A3	(0.025 REI	F				
b	0.12	0.17	0.22				
D	0.92	0.97	1.02				
E	2.20 2.25 2.30						
е	0.50 BSC						

GENERIC MARKING DIAGRAM*



= Assembly Location

WL = Wafer Lot

= Year

WW = Work Week

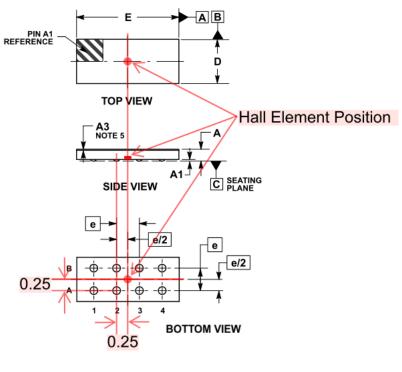
= Pb-Free Package

*This information is generic.

Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

About NOTE 5: This product has "BACKSIDE COATING".

Hall Element Position



unit: mm(typ)

Figure. Hall element position

Please refer to package diagram for each dimension.

Electrical Characteristics

Absolute maximum rating at VSS = 0 V

Item	Symbol	Condition	Rating	Unit
Supply voltage	V _{DD} 33 max	Ta ≤ 25°C	-0.3 to +4.6	V
Input/output voltage	V _I 33,V _O 33	Ta ≤ 25°C	–0.3 to V _{DD} 33+0.3	٧
Storage ambient temperature	Tstg		-55 to +125	°C
Operating ambient temperature	Topr		−30 to +70	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Acceptable operation range at Ta = -30 to 70°C, VSS = 0 V

3 V power supply (VDD)

Item	Symbol	Min	Тур	Max	Unit
Supply voltage	V _{DD} 33	2.6	2.8	3.3	V
Input voltage range	V_{IN}	0		V _{DD} 33	V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC characteristics : Input/output level at V_{SS} = 0 V, V_{DD} = 2.6 V to 3.3 V, Ta = -30 to +70°C

=							
Item	Symbol	Condition	Min	Тур	Max	Unit	Applicable pins
High-level input voltage	VIH	CMOS	1.4			>	SCL, SDA,
Low-level input voltage	VIL	compliant Schmidt			0.4	>	PORT
High-level output voltage	VOH	IOH= -2 mA	V _{DD} -0.4			V	PORT
Low-level output voltage	VOL	IOL= -2 mA			0.2	V	SDA, PORT
Pulldown resistor	Rdn		50		220	kΩ	PORT

Driver output (OUT1, OUT2) at $V_{SS} = 0 \text{ V}$, $V_{DD} = 2.8 \text{ V}$, Ta = 25°C

	Item	Symbol	Condition	Min	Тур	Max	Unit	Applicable pins
Maxi	mum current	Ifull		133	140	147	mA	OUT1, OUT2

Non-volatile Memory Characteristics

Item	Symbol	Condition	Min	Тур	Max	Unit	Applicable circuit	
Endurance	EN				1000	Cycles		
Data retention	RT		10			Years	EEPROM	
Write time	tWT				20	ms		

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

AC Characteristics

VDD supply timing

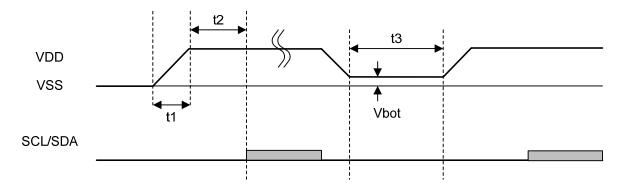


Figure. V_{DD} supply timing

It is available to use 2-wire serial interface 5 ms later for Power On Reset of VDD.

Item	Symbol	Min	Тур	Max	Unit
V _{DD} turn on time	t1			3	ms
2-wire serial interface start time from V _{DD} on	t2	5			ms
V _{DD} off time	t3	100			ms
Bottom Voltage	Vbot			0.1	V

AC specification

The figure below shows interface timing definition and following table shows electric characteristics.

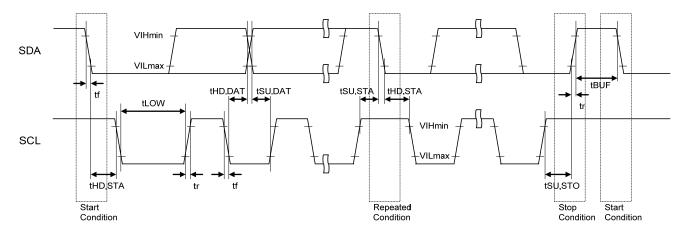


Figure. 2-wire serial interface timing definition

Table. Electric characteritics for 2-wire serial interface (AC characteristics)

Itom	Symbol Din name		Fast-mode			Fast	l lmit		
Item	Symbol	Pin name	Min	Тур	Max	Min	Тур	Max	Unit
SCL clock frequency	FSCL	SCL			400			1000	kHz
START condition hold time	tHD,STA	SCL SDA	0.6			0.26			μs
SCL clock Low period	tLOW	SCL	1.3			0.5			μs
SCL clock High period	tHIGH	SCL	0.6			0.26			μs
Setup time for repetition START condition	tSU,STA	SCL SDA	0.6			0.26			μs
Data hold time	tHD,DAT	SCL SDA	0 (*3)		0.9	0 (*3)			μs
Data setup time	tSU,DAT	SCL SDA	100			50			ns
SDA, SCL rising time	tr	SCL SDA			300			120	ns
SDA, SCL falling time	tf	SCL SDA			300			120	ns
STOP condition setup time	tSU,STO	SCL SDA	0.6			0.26			μs
Bus free time between STOP and START	tBUF	SCL SDA	1.3			0.5			μs

^{*3:} LC898219XI is designed for a condition with typ. 20 ns of hold time. If SDA signal is unstable around falling point of SCL signal, please implement an appropriate treatment on board, such as inserting a resistor.

ORDERING INFORMATION

Device	Package	Shipping (Qty / Packing)
LC898219XI-MH	WLCSP8, 0.97x2.25x0.265 (Pb-Free / Halogen Free)	4000 / Tape & Reel

[†] For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. http://www.onsemi.com/pub_link/Collateral/BRD8011-D.PDF

Development product sample is a product that intend to verify whether it is matched the customer's application spec. We kindly ask you to evaluate surely and enough prior mass-production. Please contact our sales, if there are any problems.

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officer